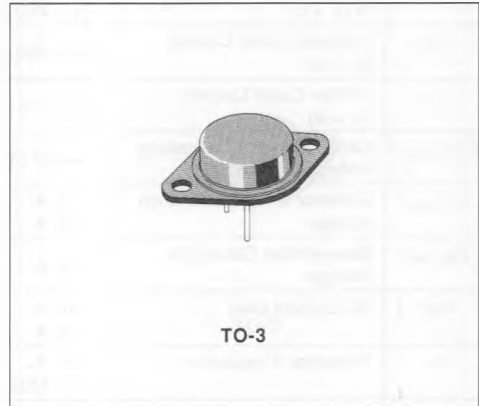




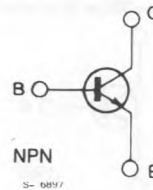
HIGH VOLTAGE POWER SWITCH

DESCRIPTION

The BUX43 is a silicon multiepitaxial mesa NPN transistor in Jedec TO-3 metal case, intended for high voltage, fast switching applications.



INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter Voltage ($V_{BE} = 0$)	400	V
V_{CER}	Collector-emitter Voltage ($R_{BE} \leq 100 \Omega$)	360	V
V_{CEO}	Collector-emitter Voltage ($I_B = 0$)	325	V
V_{EBO}	Base-emitter Voltage ($I_C = 0$)	7	V
I_C	Collector Current	10	A
I_{CM}	Collector Peak Current ($t_p \leq 10$ ms)	12	A
I_B	Base Current	2	A
P_{tot}	Total Power Dissipation at $T_{case} \leq 25$ °C	120	W
T_{stg}	Storage Temperature	- 65 to 200	°C
T_j	Junction Temperature	200	°C

THERMAL DATA

$R_{th\ i-case}$	Thermal Resistance Junction-case	Max	1.46	°C/W
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ELECTRICAL CHARACTERISTICS ($T_{case} = 25\text{ °C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector Cutoff Current ($V_{BE} = 0$)	$V_{CE} = 400\text{ V}$ $V_{CE} = 400\text{ V}$ $T_{case} = 125\text{ °C}$			1 5	mA mA
I_{CEO}	Collector Cutoff Current ($I_B = 0$)	$V_{CE} = 260\text{ V}$			1	mA
I_{EBO}	Emitter Cutoff Current ($I_C = 0$)	$V_{EB} = 7\text{ V}$			1	mA
$V_{CEO(sus)}^*$	Collector-emitter Sustaining Voltage ($I_B = 0$)	$I_C = 100\text{ mA}$	325			V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = 3\text{ A}$ $I_B = 0.375\text{ A}$ $I_C = 5\text{ A}$ $I_B = 1\text{ A}$			1 1.6	V V
$V_{BE(sat)}^*$	Base-emitter Saturation Voltage	$I_C = 5\text{ A}$ $I_B = 1\text{ A}$			2	V
h_{FE}^*	DC Current Gain	$I_C = 3\text{ A}$ $V_{CE} = 4\text{ V}$ $I_C = 5\text{ A}$ $V_{CE} = 4\text{ V}$	15 8		60	
f_T	Transition Frequency	$I_C = 1\text{ A}$ $V_{CE} = 15\text{ V}$ $f = 10\text{ MHz}$	8			MHz
t_{on}	Turn-on Time	$I_C = 5\text{ A}$ $I_{B1} = 1\text{ A}$ $V_{CC} = 150\text{ V}$			1	μs
t_s	Storage Time	$I_C = 5\text{ A}$ $I_{B1} = -I_{B2} = 1\text{ A}$ $V_{CC} = 150\text{ V}$			2.2	μs
t_f	Fall Time				1.2	μs

* Pulsed : pulse duration = 300 μs , duty cycle $\leq 2\%$.